Room temperature vibrational photoluminescence and field emission of nanoscaled tris-(8-hydroxyquinoline) aluminum crystalline film

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The nanoscaled tris-(8-hydroxyquinoline) aluminum (AlQ3) crystalline film was synthesized by vapor condensation. It was stacked with nanometer-sized rods, approximately 100 nm wide and 1 μm long, and had a surface roughness of about 100 nm. The vibronic progression with several separated peaks was observed in the photoluminescence spectrum at room temperature. It is attributed to the crystallinity of AlQ3 and the coupling of vibrations of the individual ligands to the fluorescence transition. The emission current was also observed with a turn-on field of 12.0 V/μm, and a current density of about 0.8 mA/cm² at 22 V/μm. Therefore, the AlQ3 crystalline film provides a choice for field emission.

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Recently, a lot of attention has been paid to conducting polymers and small-molecule organic semiconductors due to many unique properties such as flexibility, high photoconductive, and nonlinear optical effects that may offer applications in optoelectronic devices. Since high efficiency and polymers and small-molecule organic semiconductors due to depositing on liquid nitrogen-cooled substrates. Further, some special nanostructures could also be synthesized by the properties of AlQ3 to improve the characteristics of the electron transport layer of OLEDs. Many studies have then been focused on the thermal, electrical, and optical properties of AlQ3 to improve the characteristics of the devices. Compared with other aromatic compounds, AlQ3 has a relatively high melting point and glass transition temperature (177 °C) that contribute to the formation of amorphous AlQ3 film. The film yields a single-peaked and broadened photoluminescence (PL) spectrum under certain applied voltage or exposure to an incident laser. However, some reports revealed that crystalline AlQ3 films could be prepared by thermal evaporation on heated substrates, and some special nanostructures could also be synthesized by depositing on liquid nitrogen-cooled substrates. Furthermore, it was reported that the crystalline film had a different fluorescence quantum yield and charge mobility compared with those of the amorphous film, which was ascribed to the polymer alignment. In this work, the room temperature vibrational PL spectrum and field emission of nanoscaled AlQ3 crystalline film are presented.

Nanoscaled AlQ3 crystalline film was synthesized by vapor condensation in Ar at 1.33×10⁻³ Pa. The AlQ3 powder was placed in a graphite boat. The silicon wafer or indium tin oxide (ITO) coated glass substrate was attached under a liquid nitrogen cold trap, which was kept at 10 cm above the graphite boat. The AlQ3 powder was sublimed at a boat temperature of 400 °C, which was regulated by a power supply and a K-type thermocouple. The microstructure was observed by means of field emission gun scanning electron microscopy (FEGSEM), as shown in Fig. 1(a). The AlQ3 film is stacked by nanometer-sized rods, which are about 100 nm wide and 0.5–1 μm long. The surface morphology was also examined by atomic force microscopy (AFM), as displayed in Fig. 1(b). The roughness of the surface is about 100 nm, as shown in Fig. 1(c).

A polarization-modulation near-field scanning optical microscopy (PM–NSOM) was employed to verify the crystallinity of the nanorods. As the combination of conventional polarization microscopy and near-field scanning optical microscope provides the image of crystalline domains with a resolution less than 100 nm, it is feasible to investigate the nanocrystalline domains of the AlQ3 film. In this work, the incident laser has a wavelength of 400 nm, close to the absorption band of the AlQ3. The incident light was modulated to form a rotated linearly polarized light. In a crystalline domain, the absorption varies with the direction of linear polarization. Therefore, a dichroic ratio (R) and a phase signal (θ) can be measured through the polarization-modulation technique. The dichroic ratio (R) is defined as

\[ R = \frac{I_\parallel - I_\perp}{I_\parallel + I_\perp}, \]

where \( I_\parallel \) and \( I_\perp \) are the transmission light intensities that are parallel and perpendicular to the principal crystalline axis, respectively. The phase signal is the orientation angle where the direction of linearly polarized light coincides with the principal crystalline axis. The dichroic ratio is related to the degree of crystallinity and the phase image is related to the...
alignment direction of the domain. The dichroic and phase images of the AlQ₃ crystalline film are shown in Fig. 2. According to the dichroic image, Fig. 2(a), the crystallized regions are clearly found in the bright area. The dichroic ratio has a maximum value of about 0.37. The phase image with a value varying from 90° to 190° is displayed in Fig. 2(b). Compared to the dichroic image, the phase image reveals the directions of crystalline domains. The angle is the same in a single domain and is different for each domain.

The crystalline film of AlQ₃ has also been reported previously, although both films were grown by different mechanisms. Moulin et al. fabricated the AlQ₃ crystalline film on an oriented polytetrafluoroethylene substrate at temperatures in the range of 50–100 °C. In this work, the crystalline film was grown on an ITO substrate at −196 °C.

To check if the AlQ₃ molecules are decomposed during evaporation, the chemical bondings of the AlQ₃ crystalline film and original powder were examined by Fourier-transform infrared spectrum. Except for the peaks due to CO₂ and H₂O, all the other absorption peaks between 400 and 2000 cm⁻¹ are in good agreement with the reported results. The absorption peaks of the crystalline film are the same as those of the AlQ₃ powder, indicating that the bonding of the molecule is preserved even after evaporation at 400 °C.

The PL spectra of AlQ₃ amorphous and crystalline films deposited on silicon substrate were obtained by exciting with a He–Cd laser of a wavelength 325 nm and power 50 mW. The amorphous film of a thickness 1200Å was deposited at 1.33 × 10⁻³ Pa with a disposition rate of 3–5 Å/s controlled by a quartz monitor. It yields a strong and smooth green visible light luminescence ranging from 4500 to 7000 Å with the maximum intensity at about 5380 Å, as shown in Fig. 3(a). On the contrary, vibronic evolution of PL spectrum was observed from the AlQ₃ crystalline film, as shown in Fig. 3(b). In ordered organic molecular solids, the vibronic progression with several separated peaks have been shown previously, but only in the spectrum of AlQ₃ crystalline sample measured at 4.2 K. Here the vibronic progression in the PL spectrum of AlQ₃ crystalline film is measured at room temperature. It is reported that the splitting of the peaks is attrib-

FIG. 1. Microstructures of the AlQ₃ crystalline film: (a) FEGSEM image, (b) AFM image, and (c) roughness of surface.

FIG. 2. PM–NSOM images of the AlQ₃ crystalline film: (a) dichroic ratio image and (b) phase image.

FIG. 3. PL spectra of the AlQ₃ films: (a) amorphous and (b) crystalline.
Field emission of polycrystalline diamond film has been observed for many years. Recently, AlQ$_3$ nanowires have been fabricated and shown to exhibit field emission. The AlQ$_3$ polycrystalline film reported here is an organic semiconductor that shows field emission with a relatively low turn on voltage. The field emission properties were measured with a 50 µm gap between the anode and the cathode at a base pressure of 1.0 × 10$^{-5}$ Pa. A spherical-shaped platinum probe with an estimated area of 1.6 × 10$^{-3}$ cm$^2$ was used as the anode. The AlQ$_3$ polycrystalline film was deposited on an ITO coated glass substrate and acted as the cathode. The field emission instrument has a sphere-to-plate geometry rather than plane-to-plane, because the platinum probe provides precise motion and manipulation inside the high vacuum environment. Therefore, the field emission properties in any region of the film can be measured. The field emission characteristics are presented by the curve of current density $J$ versus applied field $E$, as shown in Fig. 5(a). The turn-on field is 12.0 V/µm when the current density reaches 0.01 mA/cm$^2$. The field emission yields a current density of about 0.8 mA/cm$^2$ at 22 V/µm. The Fowler–Nordheim plot of $\ln(J/E^2)$ vs $1/E$, shown in the inset of Fig. 5(a), yields a straight line demonstrating the field emission phenomenon.

The stability test of the AlQ$_3$ polycrystalline film was performed with an initial current density of about 0.35 mA/cm$^2$ and an applied field of 20 V/µm for more than 2000 s, as illustrated in Fig. 5(b). The field emission current varied when different region of the film was measured by the platinum probe. It revealed that the field emission current was strongly dependent on the surface roughness of the film. According to the AFM image shown in Fig. 1(c), the polycrystalline film is stacked with nanometer-sized rods and the roughness of the surface depth is about 100 nm. It demonstrates that the electrons may emit from the bumps of the AlQ$_3$ film at high voltages. The effect of surface roughness on electron emission from polycrystalline diamond films has been reported, but the same mechanism for a small molecular organic semiconductor is demonstrated here.

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